

L Number	Hits	Search Text	DB	Time stamp
1	5	Strengthening adj insulator	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/15 08:21
8	4549	Strength\$5 near insulat\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/15 08:26
15	2568	(( (257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.) ((257/443,448).CCLS.) and (Strength\$5 near insulat\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/15 08:22
22	7	(( (257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.) ((257/443,448).CCLS.)) and (Strength\$5 near insulat\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/15 08:36
29	60	(( (257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.) ((257/443,448).CCLS.)) and Strength\$5 with insulat\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/15 08:27
36	2	("5789737").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/15 08:44
43	6	5789737.URPN.	USPAT	2002/11/15 08:45
44	6	("4547074"   "5017989"   "5164809"   "5262649"   "5369281"   "5475212").PN.	USPAT	2002/11/15 08:45
45	45	5262649.URPN.	USPAT	2002/11/15 08:51
46	15	("Re32164"   "4250385"   "4288264"   "4525628"   "4626688"   "4672454"   "4679212"   "4707608"   "4785186"   "4799094"   "4823369"   "4982095"   "5017990"   "5019711"   "5079426").PN.	USPAT	2002/11/15 08:51
47	3	5959312.URPN.	USPAT	2002/11/15 09:26
48	11	("4571348"   "4842892"   "4959700"   "5262649"   "5348892"   "5360744"   "5473168"   "5480818"   "5516712"   "5599403"   "5767531").PN.	USPAT	2002/11/15 09:26
-	1395	air adj gap with remov\$3	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 15:01
-	1086	air adj gap and (438/\$ 257/\$) not (air adj gap with remov\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/09/25 10:02
-	51	forming near3 air adj gap and (air adj gap and (438/\$ 257/\$) not (air adj gap with remov\$3) )	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:05
-	13393	air and (tft tfts thin adj film adj transistor\$1 pixel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/13 15:03
-	1463	air and (tft tfts thin adj film adj transistor\$1 pixel) and (438/\$6 257/\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:05

-	191	air near2 (gap\$1 hole\$1 insulat\$4 dielectric) and (tft tfts thin adj film adj transistor\$1 pixel) and (438/\$6 257/\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 08:58
-	1149	air with line\$1 and (438/\$6 257/\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 09:00
-	47	air and (tft tfts thin adj film adj transistor\$1 pixel) and (438/\$6 257/\$6) and (air with line\$1 and (438/\$6 257/\$6))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 15:54
-	1216	((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN. or (257/13,81,91,918,307).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:41
-	0	((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN. or (257/13,81,91,918,307).CCLS.) and air with ((first and second) near line\$1 line\$1 near (gate and data))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:04
-	0	((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN. or (257/13,81,91,918,307).CCLS.) and air with ((first and second) near2 line\$1 line\$1 near2 (gate and data))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:06
-	0	((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN. or (257/13,81,91,918,307).CCLS.) and air with ((first second) near2 line\$1 line\$1 near2 (gate data))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:06
-	3073	forming near3 air adj (gap\$1 hole\$1 insulat\$4 dielectric space\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:08
-	0	(forming near3 air adj (gap\$1 hole\$1 insulat\$4 dielectric space\$1) ) and ((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN. or (257/13,81,91,918,307).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:09
-	6203	forming near3 air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:09
-	0	(forming near3 air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) ) and ((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN. or (257/13,81,91,918,307).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:41
-	16	air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) and ((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN. or (257/13,81,91,918,307).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:43
-	2040	air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) and pixel\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:15
-	1744	air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) with (cross adj over crossover intersect\$4 over adj lap\$4 overlap\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:26

-	1805	air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) with (cross adj over crossover intersect\$4 over adj lap\$4 overlap\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:36
-	0	(air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) with (cross adj over crossover intersect\$4 over adj lap\$4 overlap\$4) ) and (((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN. or (257/13,81,91,918,307).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:42
-	0	((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:42
-	1352	(257/E29.151,E29.117,E29.202,E29.273).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:20
-	1	((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN. or (257/13,81,91,918,307).CCLS.) and ((257/E29.151,E29.117,E29.202,E29.273).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:42
-	2567	((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN. or (257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:21
-	0	(air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) with (cross adj over crossover intersect\$4 over adj lap\$4 overlap\$4) ) and (((("E29.151") or ("E29.117") or ("E29.202") or ("E29.273"))).PN. or (257/13,81,91,918,307).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:43
-	5	air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) and ((257/E29.151,E29.117,E29.202,E29.273).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 10:45
-	59	(air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) with (cross adj over crossover intersect\$4 over adj lap\$4 overlap\$4) ) and (438/\$6 257/\$6)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 17:26
-	1	air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) with (each every all) near2 (cross adj over crossover intersect\$4 over adj lap\$4 overlap\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 11:10
-	14	air with (each every all) near2 (cross adj over crossover intersect\$4 over adj lap\$4 overlap\$4)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 11:13
-	1387	(257/443,448).CCLS.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 15:45
-	0	air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) with (cross adj over crossover intersect\$4 over adj lap\$4 overlap\$4) and ((257/443,448).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 11:56

-	19	air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) and ((257/443,448).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 11:59
-	3	((bit data)near line and (word gate) near line) with air	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 12:35
-	13	((bit data)near line and (word gate) near line) same air	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:30
-	43	((257/443,448).CCLS.) and pixel adj array	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 13:54
-	2	("6107641").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 13:54
-	270	x adj ray adj imag\$3 adj sensor\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:31
-	495	x adj ray near2 imag\$3 near2 sensor\$1	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:31
-	1	(x adj ray near2 imag\$3 near2 sensor\$1) and air near2 (separat\$3 dielectric insulat\$4 space\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:36
-	8	air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1) and (x adj ray near2 imag\$3 near2 sensor\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:40
-	2	("5171996").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 14:40
-	0	("29 and amorphous with (photosensor photosensativ\$2 photosensetiv\$2 photosensitiv\$2)").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 15:13
-	35	((257/443,448).CCLS.) and amorphous with (photosensor photosensativ\$2 photosensetiv\$2 photosensitiv\$2)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 15:13
-	0	((257/443,448).CCLS.) and b adj staged near2 monomers	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 15:46
-	2	(438/\$6 257/\$6) and b adj staged near2 monomers	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 15:48

-	0	(438/\$6 257/\$6) and bisbezocyclobutene	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 15:49
-	49	(438/\$6 257/\$6) and bisbenzocyclobutene	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 15:51
-	0	(438/\$6 257/\$6) and bis adj benzocyclo adj butene	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 15:52
-	0	(438/\$6 257/\$6) and bis adj benzo adj cyclo adj butene	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 16:05
-	0	((257/443,448).CCLS.) and (((438/\$6 257/\$6) and bisbenzocyclobutene) ((438/\$6 257/\$6) and bis adj benzocyclobutene))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 15:53
-	4	(((438/\$6 257/\$6) and bisbenzocyclobutene) ((438/\$6 257/\$6) and bis adj benzocyclobutene)) and (tft tfts thin adj film adj transistor\$1 pixel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 17:12
-	24	phosphor adj converter	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 16:05
-	4	(438/\$6 257/\$6) and (phosphor adj converter)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 16:06
-	0	crossover adj structure with (gate and data)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 17:11
-	0	cross adj over adj structure with (gate and data)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 17:12
-	106	crossover adj structure	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 17:25
-	9	(crossover adj structure ) and (tft tfts thin adj film adj transistor\$1 pixel)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:15
-	15	crossover adj structure with air	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 17:18
-	358	air with pixel	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 17:25

-	1741	(air near2 (gap\$1 hole\$1 insulat\$4 dielectric space\$1)) and pixel	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 17:27
-	2	("5587591").PN.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:11
-	285	self adj align\$3 near (tft tfts thin adj film adj transistor\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:57
-	1	((257/443,448).CCLS.) and (self adj align\$3 near (tft tfts thin adj film adj transistor\$1) )	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:21
-	2567	((257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:50
-	28	((257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.) and (self adj align\$3 near (tft tfts thin adj film adj transistor\$1) )	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:21
-	25	(438/\$6 257/\$6) and bis adj benzocyclobutene	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:48
-	72	((438/\$6 257/\$6) and bisbenzocyclobutene) ((438/\$6 257/\$6) and bis adj benzocyclobutene)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:49
-	3943	((257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.) ((257/443,448).CCLS.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/15 08:21
-	0	((257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.) ((257/443,448).CCLS.) and CYCLOTENE	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:51
-	1	((257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.) ((257/443,448).CCLS.) and bisbenzocyclobutene	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:56
-	1	((257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.) ((257/443,448).CCLS.) and (bisbenzocyclobutene bis adj benzocyclobutene)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/14 18:56
-	71	((257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.) ((257/443,448).CCLS.) and bisbenzocyclobutene bis adj benzocyclobutene	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/15 08:44
-	2	((257/13,81,91,918,307).CCLS.) ((257/E29.151,E29.117,E29.202,E29.273).CCLS.) ((257/443,448).CCLS.) and bisbenzocyclobutene bis adj benzocyclobutene) and (tft tfts thin adj film adj transistor\$1)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2002/11/15 08:19